250V P-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

V(BR)DSS=-250V; $RDS(ON)=14\Omega$; ID=-205mA

DESCRIPTION

This 250V enhancement mode P-channel MOSFET provides users with a competitive specification offering efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdown. Applications benefiting from this device include a variety of Telecom and general high voltage switching circuits.





- High voltage
- Low on-resistance
- · Fast switching speed
- Low gate drive
- · Low threshold
- Complementary N-channel Type ZVN4525Z
- SOT89 package

APPLICATIONS

- · Earth Recall and dialling switches
- Electronic hook switches
- High Voltage Power MOSFET Drivers
- Telecom call routers
- Solid state relays

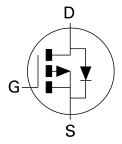
ORDERING INFORMATION

DEVICE	REEL SIZE (inches)	TAPE WIDTH (mm)	QUANTITY PER REEL
ZVP4525ZTA	7	12mm embossed	1000 units
ZVP4525ZTC	13	12mm embossed	4000 units

DEVICE MARKING

• P52









ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V _{DSS}	250	V
Gate Source Voltage	V _{GS}	±40	V
Continuous Drain Current (VGS=10V; TA=25°C)(a) (VGS=10V; TA=70°C)(a)	I _D	-205 -164	mA mA
Pulsed Drain Current (c)	I _{DM}	-1	A
Continuous Source Current (Body Diode)	IS	-0.75	А
Pulsed Source Current (Body Diode)	I _{SM}	-1	А
Power Dissipation at T _A =25°C (a) Linear Derating Factor	PD	1.2 9.6	W mW/°C
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient (a)	$R_{\theta JA}$	103	°C/W
Junction to Ambient (b)	$R_{\theta JA}$	50	°C/W

NOTES

NB High Voltage Applications

For high voltage applications, the appropriate industry sector guidelines should be considered with regard to voltage spacing between conductors.

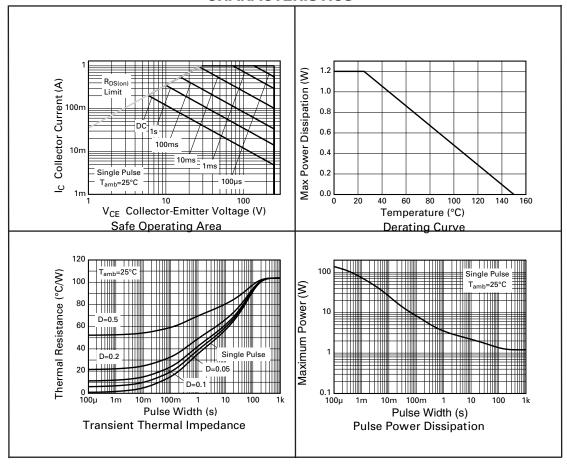


 $⁽a) For a device surface mounted on 25 mm\ x\ 25 mm\ FR4\ PCB\ with\ high\ coverage\ of\ single\ sided\ 1oz\ copper,\ in\ still\ air\ conditions$

⁽b) For a device surface mounted on FR4 PCB measured at t≤5 secs.

⁽c) Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.

CHARACTERISTICS





ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated)

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PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.	
STATIC		!		'			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	-250	-285		V	I _D =-1mA, V _G S=0V	
Zero Gate Voltage Drain Current	I _{DSS}		-30	-500	nA	V _{DS} =-250V, V _{GS} =0V	
Gate-Body Leakage	I _{GSS}		±1	±100	nA	V _{GS} =±40V, V _{DS} =0V	
Gate-Source Threshold Voltage	V _{GS(th)}	-0.8	-1.5	-2.0	V	I _D =-1mA, V _{DS} = V _{GS}	
Static Drain-Source On-State Resistance (1)	R _{DS(on)}		10 13	14 18	ΩΩ	V _{GS} =-10V, I _D =-200mA V _{GS} =-3.5V, I _D =-100mA	
Forward Transconductance (3)	9fs	80	200		mS	V _{DS} =-10V,I _D =-0.15A	
DYNAMIC (3)				•			
Input Capacitance	C _{iss}		73		pF	V _{DS} =-25 V, V _{GS} =0V, f=1MHz	
Output Capacitance	Coss		12.8		pF		
Reverse Transfer Capacitance	C _{rss}		3.91		pF	1	
SWITCHING(2) (3)		•	•	•			
Turn-On Delay Time	t _{d(on)}		1.53		ns		
Rise Time	t _r		3.78		ns	V _{DD} =-30V, I _D =-200m	
Turn-Off Delay Time	t _{d(off)}		17.5		ns	R _G =50Ω, V _G S=-10V (refer to test circuit)	
Fall Time	tf		7.85		ns		
Total Gate Charge	Ωg		2.45	3.45	nC		
Gate-Source Charge	Qgs		0.22	0.31	nC	V _{DS} =-25V,V _{GS} =-10\ I _D =-200mA(refer to	
Gate Drain Charge	Q _{gd}		0.45	0.63	nC	test circuit)	
SOURCE-DRAIN DIODE		•		'	•		
Diode Forward Voltage (1)	V _{SD}			0.97	V	T _j =25°C, I _S =-200mA, V _{GS} =0V	
Reverse Recovery Time (3)	t _{rr}		205	290	ns	T _j =25°C, I _F =-200mA, di/dt=100A/μs	
Reverse Recovery Charge (3)	Q _{rr}		21	29	nC		

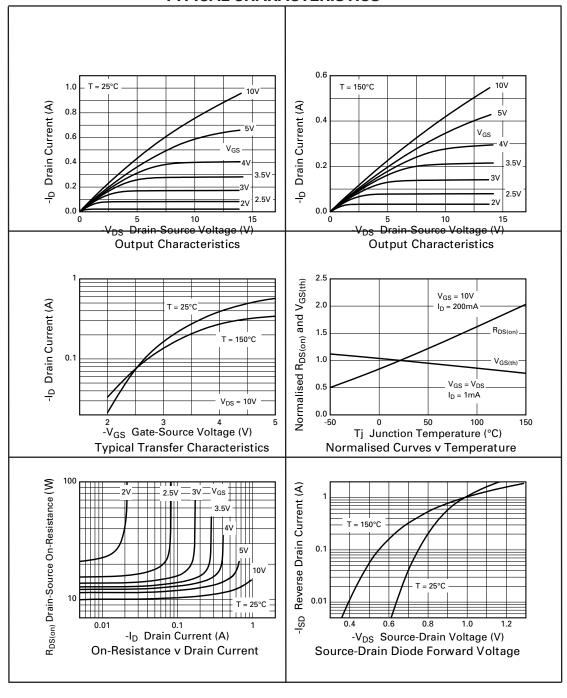
⁽¹⁾ Measured under pulsed conditions. Width=300 $\mu s.$ Duty cycle $\leq~2\%$.



⁽²⁾ Switching characteristics are independent of operating junction temperature.

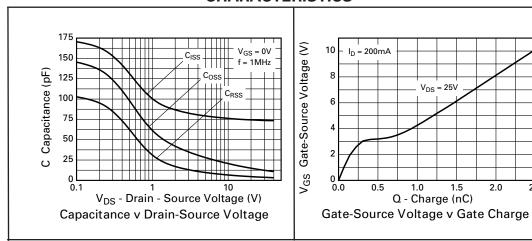
⁽³⁾ For design aid only, not subject to production testing.

TYPICAL CHARACTERISTICS



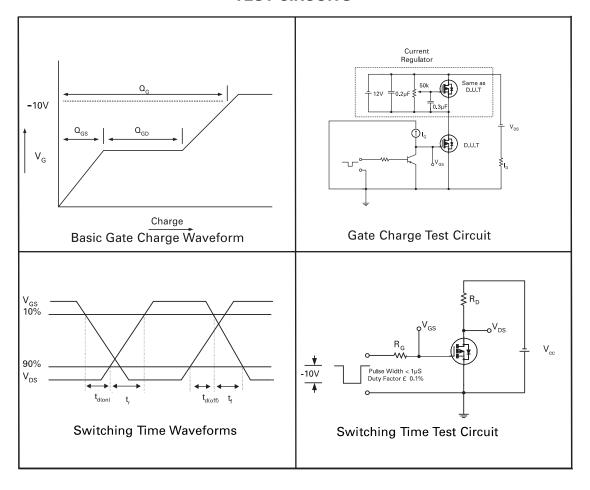


CHARACTERISTICS





TEST CIRCUITS





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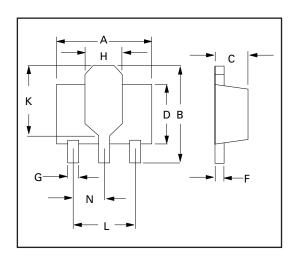
PACKAGE DIMENSIONS

DIM	Millimetres		Inches	
	Min	Max	Min	Max
А	4.40	4.60	0.173	0.181
В	3.75	4.25	0.150	0.167
С	1.40	1.60	0.550	0.630
D	-	2.60	-	0.102
F	0.28	0.45	0.011	0.018
G	0.38	0.55	0.015	0.022
Н	1.50	1.80	0.060	0.072
К	2.60	2.85	0.102	0.112
L	2.90	3.10	0.114	0.122
N	1.40	1.60	0.055	0.063

4.0

PAD LAYOUT DETAILS

SOT89 pattern.
Minimum Pad Size (dimensions in mm)



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